

Supporting Information

Defect-Tailored ZnO Nanoflowers Enable Efficient, Metal-Free Ammonia

Synthesis through Coupled Piezoelectric and Photocatalytic Activation

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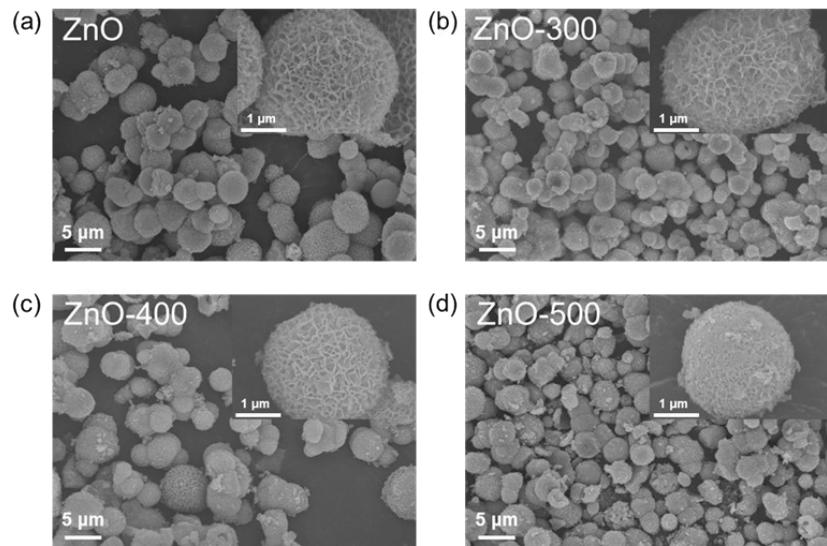


Figure S1. SEM images of (a) pristine ZnO, (b) ZnO-300, (c) ZnO-400, and (d) ZnO-500 with the high-magnification image insets.

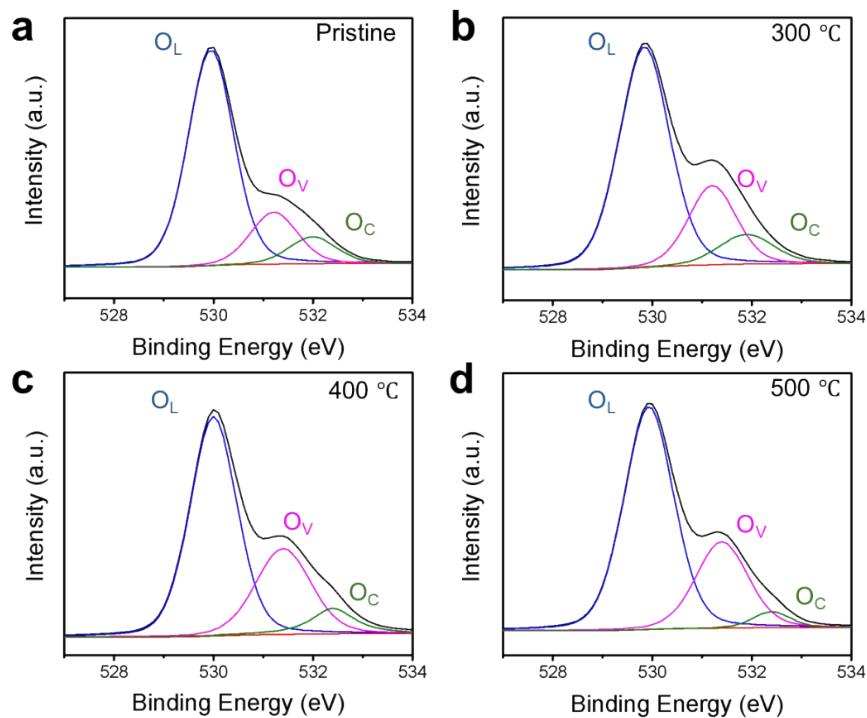


Figure S2. XPS O 1s spectra of (a) pristine ZnO, (b) ZnO-300, (c) ZnO-400, and (d) ZnO-500.

Supporting Information of S1

A gradual narrowing of the band gap is observed with increasing annealing

temperature. This redshift can be attributed to the increasing concentration of oxygen vacancies, which introduce localized defect states near the conduction band edge. These defect states effectively reduce the band gap, enhancing visible-light absorption and improving photocatalytic activity under solar irradiation. The band gap in ZnO-500 is 3.18 eV, which correlates with its highest oxygen vacancy concentration, as also supported by EPR and XPS results.

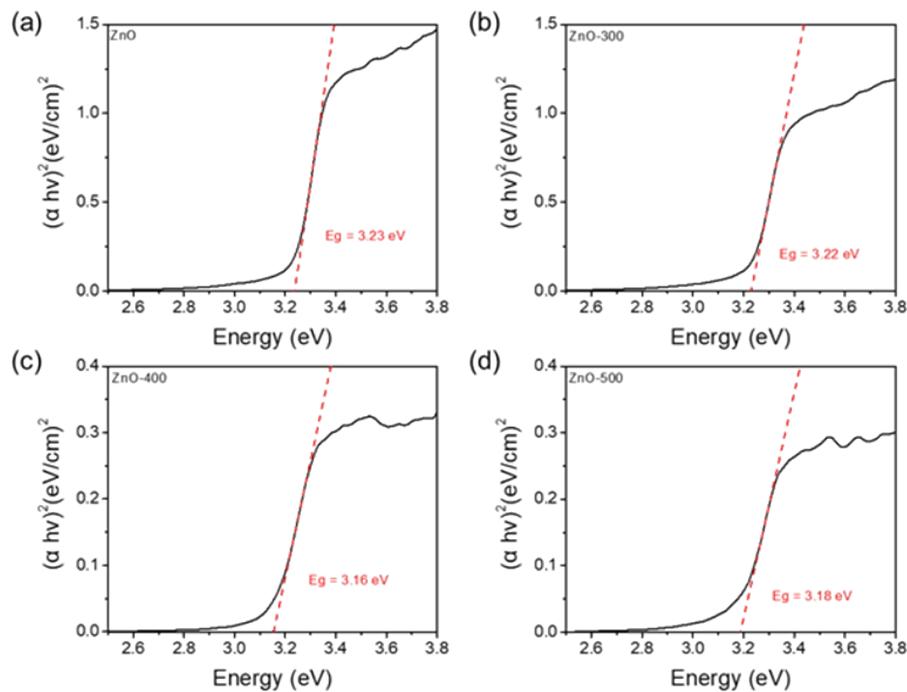


Figure S3. presents the UV–vis diffuse reflectance spectroscopy (UV-DRS) results and corresponding Tauc plots of (a) pristine ZnO, (b) ZnO-300, (c) ZnO-400, and (d) ZnO-500, used to estimate the optical band gap energies of each sample.

Supporting Information of S2

Figure S4 shows the X-ray photoelectron spectroscopy valence band maximum (XPS-VBM) spectra of ZnO samples annealed at different temperatures. The VBM values were estimated by extrapolating the linear portion of the leading edge of each spectrum to the baseline. The valence band maximum values, determined from the extrapolation of the leading edge of the XPS spectra, are 2.67 eV for pristine ZnO and

ZnO-300, 2.61 eV for ZnO-400, and 2.52 eV for ZnO-500. These results indicate a progressive downward shift of the VBM with increasing annealing temperature, especially evident in ZnO-400 and ZnO-500. This shift can be attributed to the formation of oxygen vacancies, which modify the electronic structure by introducing mid-gap states and lowering the effective VBM position. The reduced VBM suggests enhanced band bending and stronger internal electric fields, which are favorable for improved charge separation and surface redox activity during the photocatalytic and piezocatalytic nitrogen reduction reaction (NRR).

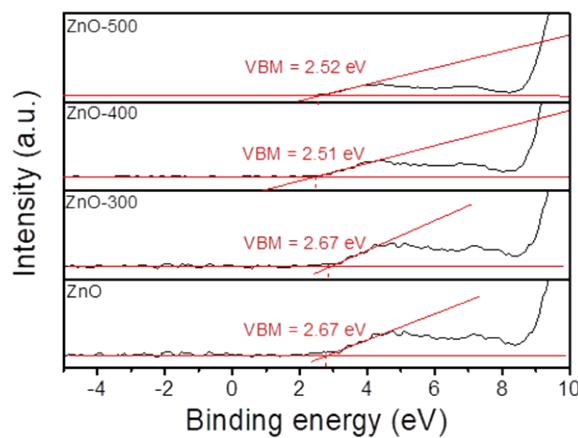


Figure S4. XPS-VBM results of ZnO under different annealing temperatures indicating the valence band maximum of each sample.

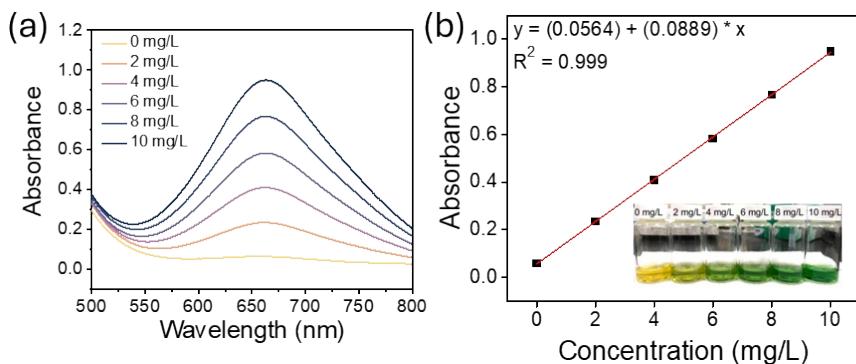


Figure S5. Calibration curve of the indophenol blue method (a) UV-vis spectra and (b) the calibration curve of absorbance and ammonia concentration.

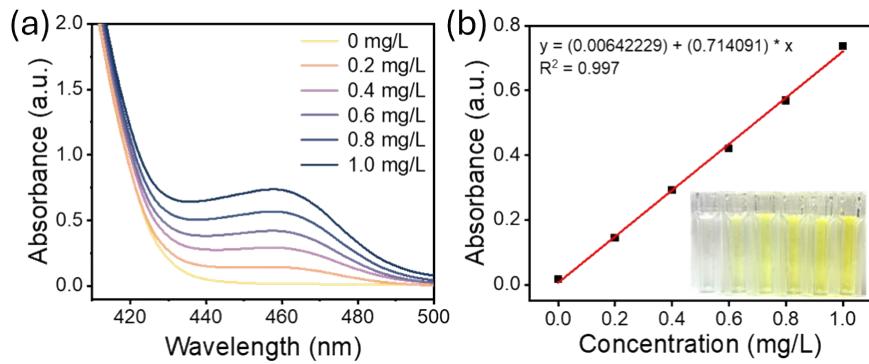


Figure S6. Calibration curve of the Watt and Chrissp method (a) UV-vis spectra and (b) the calibration curve of absorbance and N₂H₄ concentration.

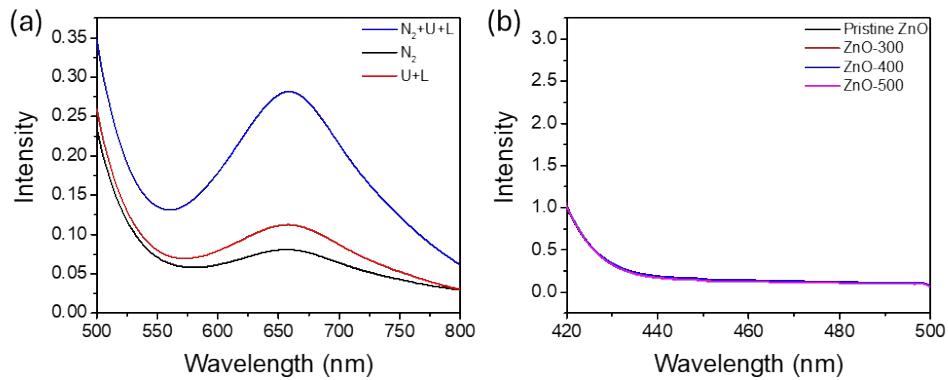


Figure S7. (a) UV-vis spectra of ZnO-300 under different catalytic conditions. U: ultrasonication, L: light irradiation, and N₂: N₂ pumping. (b) UV-vis spectra for Watt and Chrissp method of the ZnO NFs under different annealing temperatures.

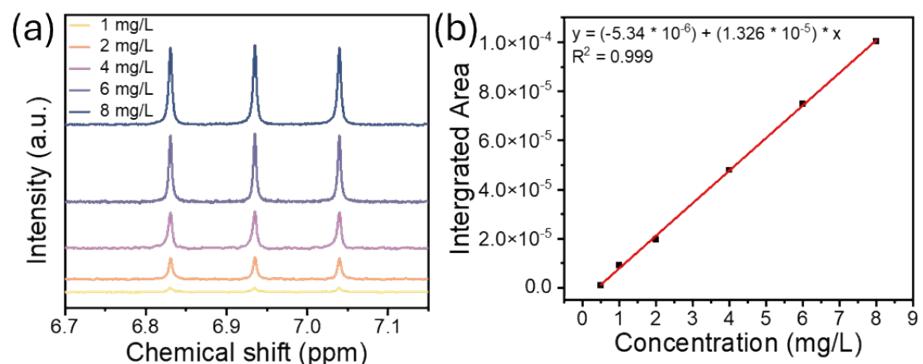


Figure S8. Calibration curve of the NMR quantification method (a) NMR spectra and (b) the calibration curve of NMR integrated area and ammonia concentration.

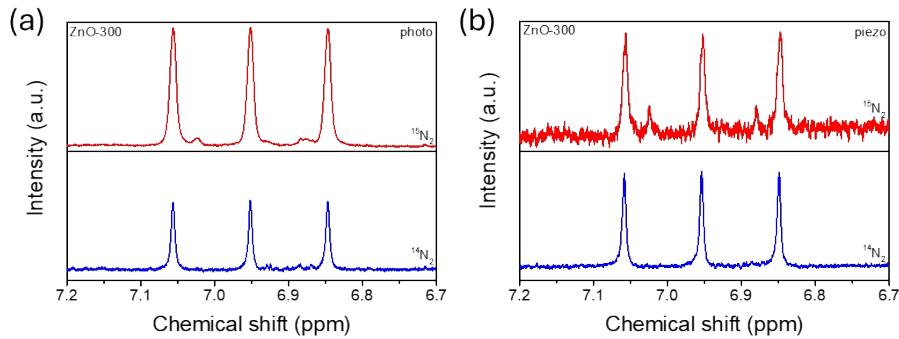


Figure S9. NMR spectra of $^{15}\text{NH}_4^+$ and $^{14}\text{NH}_4^+$ detection of ZnO-300 through (a) photocatalytic process and (b) piezocatalytic process.

Table S1. Comparison table of NH_3 production rates using different catalytic sources and catalysts.

Catalytic source	Catalyst	NH_3 production rate	Reference
Piezo/Photo	ZnO-O _V	$1765.3 \mu\text{g g}_{\text{cat}}^{-1} \text{h}^{-1}$	This work
Photo	Fe-TiO ₂	$1091.4 \mu\text{g g}_{\text{cat}}^{-1} \text{h}^{-1}$	[1]
Photo	Fe-Bi ₂ MoO ₆	$1810.5 \mu\text{g g}_{\text{cat}}^{-1} \text{h}^{-1}$	[2]
Photo	g-C ₃ N ₄ -C _V	$1428 \mu\text{g g}_{\text{cat}}^{-1} \text{h}^{-1}$	[3]
Piezo	Ag/ZnO	$66.64 \mu\text{g g}_{\text{cat}}^{-1} \text{h}^{-1}$	[4]
Piezo	Ag/Bi ₅ O ₇ I	$1111.8 \mu\text{g g}_{\text{cat}}^{-1} \text{h}^{-1}$	[5]
Piezo/Photo	BaTiO ₃ -O _V	$1813.9 \mu\text{g g}_{\text{cat}}^{-1} \text{h}^{-1}$	[6]

Supporting Information of S3

Calculation details

Initially, the unit cell of ZnO was relaxed using a $10 \times 10 \times 6$ gamma-centered k-point mesh. Subsequently, to explore the surface properties of the ZnO (100) surfaces, a 2×2 supercell with a ZnO (100) surface was constructed. Then the oxygen vacancy

defect was introduced on the surface. The final model can be divided into pristine ZnO and ZnO-O_V for further computation, as shown in Figure S10. To maintain a similar k-point density in the supercell as in the unit cell, the k-point mesh was adjusted to a 5 × 3 × 1 gamma-centered mesh. The surface model comprised six layers, with the lower three layers constrained to their bulk configuration throughout all calculations. Additionally, a vacuum layer with a width of 20 Å was included to prevent interactions between periodic images. The adsorption energy E_{ads} of N₂ on the surface of ZnO was calculated through the following equation:

$$E_{ads} = E_{total} - E_{surface} - E_{N_2}$$

where E_{total}, E_{N₂}, and E_{surface} are the total energies of the adsorbed system, isolated nitrogen molecules, and pristine surface, respectively.

In order to compute partial atomic charges for all systems, we performed charge analysis calculations to determine the Bader charge and charge density difference (CDD) for ZnO. The CDD can be obtained by following the equation:

$$CDD = Charge\ density_{total\ system} - Charge\ density_{surface} - Isolated_{N_2}$$

Density of state analysis has also been conducted to investigate the energy band structure of ZnO and ZnO-O_V and the defect state formation. The model of ZnO-O_V with different percent biaxial strain has also been made in order to simulate the applied stress on the piezoelectric ZnO surface.

The reaction free energy was calculated by following the equation:

$$E_{free} = E_{total} - E_{surface} - n\mu_N - m\mu_H$$

where E_{total} and E_{surface} are the total energies of the adsorbed system and bare surface, respectively. And μ_N and μ_H are the chemical potentials of the nitrogen atom and hydrogen atom, respectively[7].

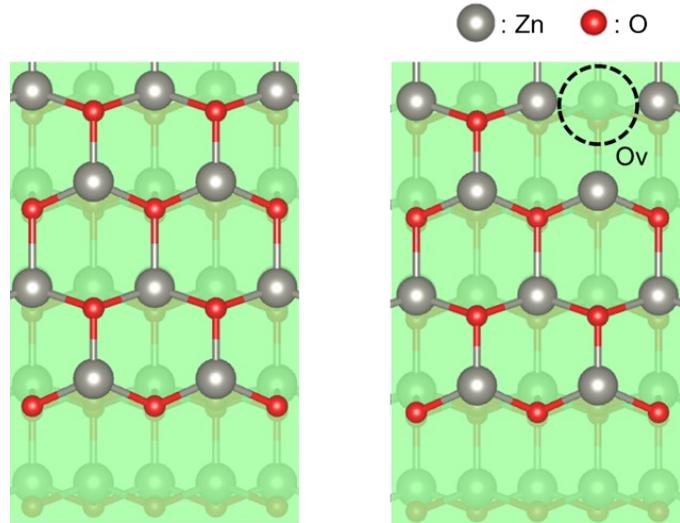


Figure S10. DFT calculation model of pristine ZnO (100) slab (left) and ZnO (100) slab with oxygen vacancy (right).

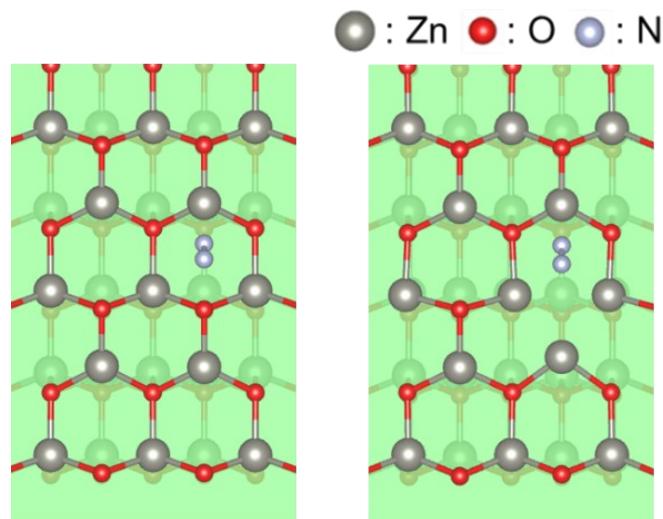


Figure S11. DFT model of pristine ZnO (left) and ZnO-O_v (right) after the adsorption of nitrogen by end-on mode at the hollow sites.

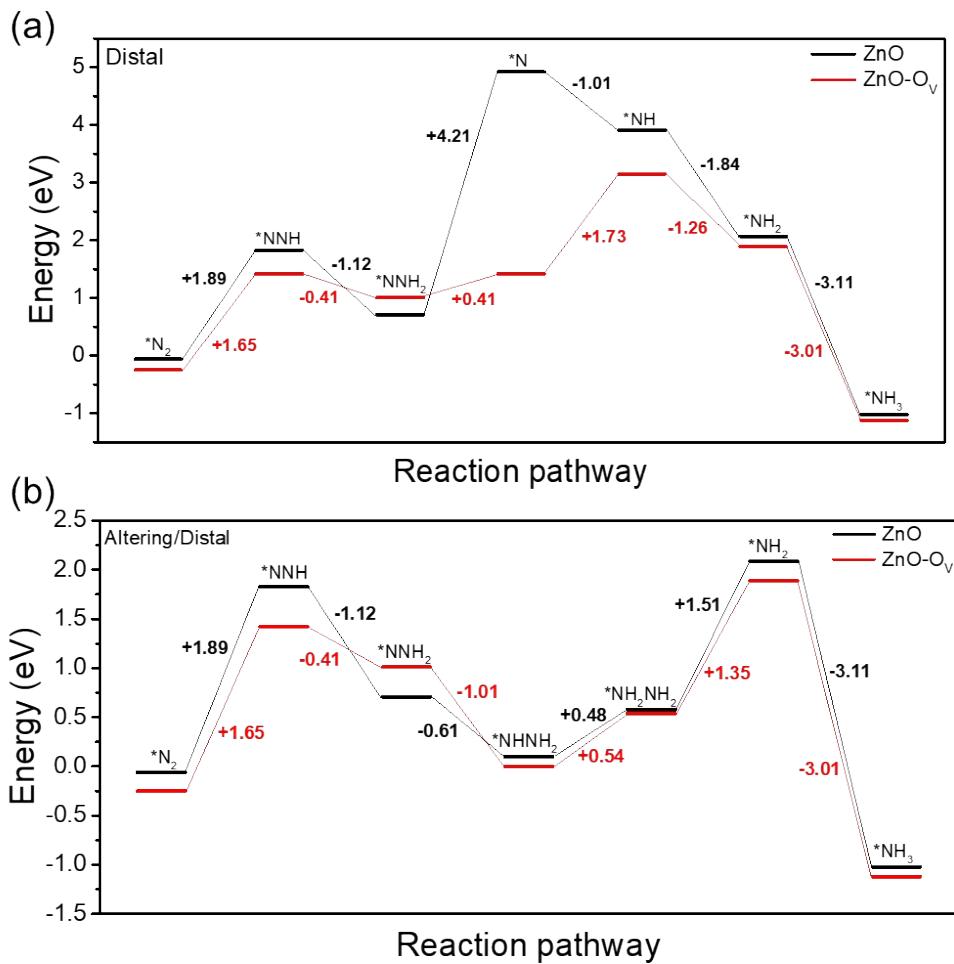
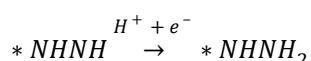
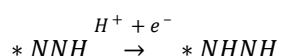
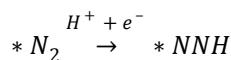


Figure S12. NRR free energy diagram of ZnO and ZnO-O_V through (a) associative distal pathway and (b) mix pathway. The calculation results indicate that the energy barrier of the distal pathway is larger, thus it is not energy-favorable in our system.

Supporting Information of S4

Hydrogenation sequences of associative altering pathway, indicating the transition from *N_2 to *NH_3 .



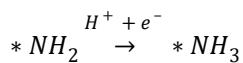
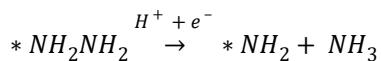
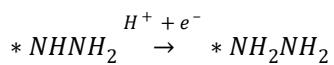


Table S2. Composition of the indophenol blue indicator.

Solution	Composition
A	4.97 g salicylic acid + 4.39 g sodium citrate in 100 ml, 0.625 M KOH solution
B	$\text{C}_5\text{FeN}_6\text{Na}_2\text{O}$ solution (10 mg/ml)
C	4% NaClO solution

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